

# 600mA, 500KHz, Synchronous Step-Up DC-DC Converter UM3429S SOT23-6

# **General Description**

The UM3429S is synchronous rectified, fixed frequency, step-up DC/DC converter series delivering high efficiency in low profile SOT23-6 package. It features true output load disconnection and adjustable output. With an internal NMOS switch, PMOS synchronous rectifier and high switching frequency of 500KHz, the UM3429S is capable of supplying 3.3V output at 100mA from a single AA cell input or 250mA from a 2-cell AA input using low profile inductors and ceramic capacitors. Current mode PWM control with internal compensation as well as the synchronous rectifier and 500KHz high frequency lead to the fewest number of external parts needed, thereby saving BOM cost and PCB area. At light load, UM3429S automatically enters into pulse skipping mode to keep high efficiency. An internal resistor will be connected to  $V_{\rm IN}$  when the switch is idle that eliminates switch ringing and reduces EMI interference. The device also features low shutdown current lower than  $1\mu A$ , inrush current limit.

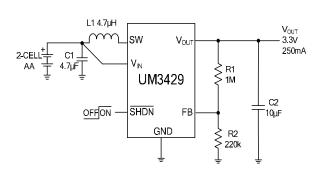
# **Applications**

- Digital Cameras
- LCD Bias Supplies
- Handheld Instruments
- Wireless Handsets
- GPS Receivers
- All one cell \( \) tow cell alkaline
   NiCD \( \) NiMH or Li-ion battery
   Powered products

#### **Features**

- Up to 92% Efficiency
- Output Load Disconnection
- Internal Synchronous Rectifier
- Low Voltage Start-Up: 0.85V
- Input Current Limit
- Pulse Skipping Mode Operation with Typical I<sub>O</sub> as 20μA
- Shutdown Current Lower than 1μA
- 500KHz Switching Frequency for Low Profile Inductor/Capacitor
- Input Voltage: 0.5V to 5.0V
- Output Voltage: 2.5V to 5V
- Anti-Ringing Control to Reduce EMI

# **Typical Application Circuit**

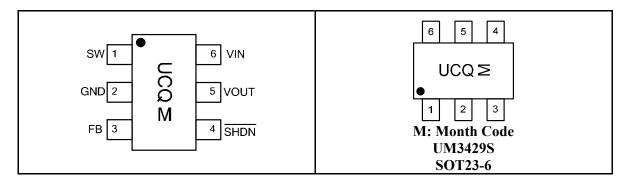


# Efficiency vs. Output Current 100 95 V<sub>OUT</sub>=3.3V 99 0 85 80 75 65 60 V<sub>IN=1.5V</sub> V<sub>IN=1.5V</sub> V<sub>IN=2.4V</sub> V<sub>IN=3.0V</sub> 100 Output Current(mA)



# **Pin Configurations**

# **Top View**



# **Pin Description**

Pin Number	Symbol	Description
1	SW	Switch Pin. Connect external inductance to $V_{\rm IN}$ . Keep these PCB trace lengths as short and wide as possible.
2	GND	Ground. Provide a short direct PCB path between GND and the negative electrode of $C_{\rm OUT}$ and $C_{\rm IN}$ .
3	FB	Feedback Input Pin. Connect to the center point of the external resistor divider and set the output voltage by: $V_{OUT} = 0.6V \left(1 + \frac{R1}{R2}\right)$
4	SHDN	Logic Controlled Shutdown Input. Low logic active. In shutdown mode, all functions are disabled drawing <1µA supply current. Do not leave SHDN floating.
5	VOUT	Output Voltage Sense Input and Drain of the Internal Synchronous Rectifier P-MOSFET. Bias is derived from $V_{\text{OUT}}$ . Keep PCB trace length from $V_{\text{OUT}}$ to the output filter capacitor(s) as short and wide as possible.
6	VIN	Battery Input Voltage. The device gets its start-up bias from $V_{\rm IN}$ . Once $V_{\rm OUT}$ exceeds $V_{\rm IN}$ , bias comes from $V_{\rm OUT}$ . Thus, once started, operation is completely independent from $V_{\rm IN}$ . Operation is only limited by the output power level and the battery's internal series resistance.

# **Ordering Information**

Part Number	Packaging Type	Marking Code	Shipping Qty
UM3429S	SOT23-6	UCQ	3000pcs/7Inch Tape & Reel



# **Absolute Maximum Ratings (Note 1)**

Symbol	Parameter	Value	Unit
$ m V_{IN}$	V <sub>IN</sub> Supply Voltage	-0.3 to +6.0	V
$V_{\mathrm{SW}}$	SW Voltage	-0.3 to +6.0	V
$ m V_{FB}$	FB Voltage	-0.3 to +6.0	V
$ m V_{\overline{SHDN}}$	SHDN Voltage	-0.3 to +6.0	V
$V_{ m OUT}$	Output Voltage	-0.3 to +6.0	V
$T_{OP}$	Operating Temperature Range	-40 to +85	°C
$T_{STG}$	Storage Temperature Range	-65 to +150	°C
$T_{\rm L}$	Maximum Lead Temperature (Soldering, 10s)	+260	°C

Note 1: Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

#### **Thermal Information**

$P_{\mathrm{D}}$	Power Dissipation at $T_A = 25^{\circ}C$ (Note 4)	0.657	W	
	Power Dissipation at $T_A = 70^{\circ}C$	0.421		
$\theta_{ m JA}$	Package Thermal Resistance (Note2, 3)	190	°C/W	
$T_{J}$	Operating Junction Temperature	+150	°C	
$T_{STG}$	Storage Temperature Range	-65 to +150	°C	
$T_{\rm L}$	Maximum Lead Temperature for Soldering 10 seconds	+260	°C	

Note 2: Junction to Ambient thermal Resistance is highly dependent on PCB layout.

Note 3:  $\theta_{JA}$  is measured in the convection at  $T_A$ =25°C (or  $T_A$ =70°C)on a High effective thermal conductivity test board of JESD51-7 thermal measurement standard

Note 4: The maximum recommended junction temperature ( $T_J$ ) of the UM3429S is 150°C,the thermal resistance of the UM3429S is  $R_{\Theta JA}$ =190°C/W, specified regulator operation is assured to a maximum ambient temperature  $T_A$  of 25°C .there for the maximum power dissipation is calculated as below:

$$P_{D(MAX)} = \frac{T_J(max) - T_A}{R_{BIA}} = \frac{150 - 25}{190} = 0.657W$$



# **Electrical Characteristics**

 $(V_{IN}=+1.2V, V_{OUT}=+3.3V, T_A=+25$ °C, unless otherwise noted.)

Parameter	Test Conditions	Min	Тур	Max	Unit	
Minimum Start-up Voltage	I <sub>LOAD</sub> =1mA, V <sub>OUT</sub> =0V		0.85		V	
Minimum Operating Voltage	SHDN=V <sub>IN</sub> (Note 5)		0.5	0.65	V	
Maximum Input Voltage				5	V	
Adjustable Output Voltage Range		2.5		5	V	
Feedback Voltage		0.595	0.6	0.605	V	
Feedback Input Current	$V_{FB}=0.6V$		1	50	nA	
Quiescent Current (Pulse Skipping Mode)	$V_{IN}=\frac{V_{FB}=0.7V_{,}}{V_{IN}=\overline{SHDN}}$ (Note 6)		20		μА	
Quiescent Current (Normal)	$V_{IN} = \frac{V_{FB} = 0.5 \text{V}}{\text{SHDN}} \text{ (Note 6)}$		0.8		mA	
Quiescent Current (Shutdown)	SHDN=0V			1	μΑ	
NMOS Leakage Current	$V_{SW}=5V$			5	μΑ	
PMOS Leakage Current	$V_{SW}=5V$ , $V_{OUT}=0V$			5	μΑ	
NMOS On-Resistance			0.4		Ω	
PMOS On-Resistance			0.5		Ω	
NMOS Current limit			850		mA	
Pulse Skipping Mode Operation Current Threshold	L=4.7μH		5		mA	
Max Duty Cycle		80	90		%	
Switching Frequency			500		KHz	
SHDN Input High		1			V	
SHDN Input Low				0.35	V	
SHDN Input Current	SHDN=5.5V		0.01	1	μΑ	
ESD AND LATCH UP PERFORMANCE						
I/O Pin ESD-Protection Voltage	Human Body Mdoel		±2		KV	
Latch Up Performance	JEDEC Standard No.78E		±200		mA	

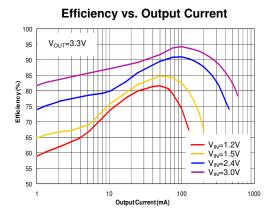
Note 5: Minimum  $V_{\rm IN}$  operation after start-up is only limited by the battery's ability to provide the necessary power as it enters a deeply discharged state.

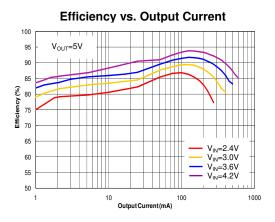
Note 6: Pulse skipping mode and normal operation  $I_Q$  is measured at  $V_{OUT}$ . The chip is in the open loop status and the inductor should not be soldered.

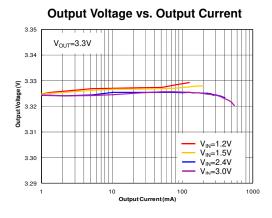


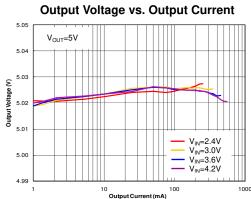
# **Typical Operating Characteristics**

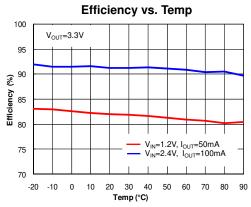
 $(C_{IN}=4.7\mu\text{F}, C_{OUT}=10\mu\text{F}, L=4.7\mu\text{H}, T_A=25^{\circ}\text{C}, \text{ unless otherwise specified})$ 

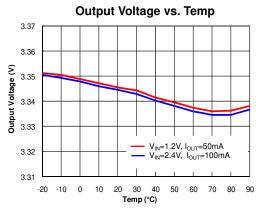


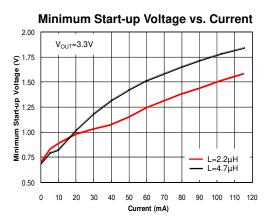


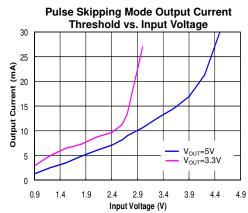










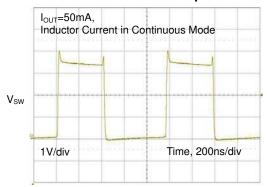




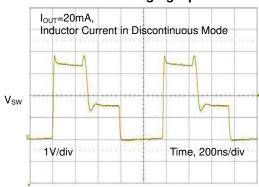
# **Typical Operating Characteristics (Continued)**

 $(V_{IN}=1.5V, V_{OUT}=3.3V, C_{IN}=4.7\mu F, C_{OUT}=10\mu F, L=4.7\mu H, T_A=25^{\circ}C, unless otherwise specified)$ 

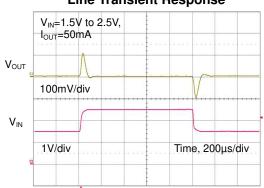
# **SW Pin Normal Mode Operation**



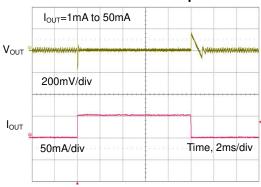
## **SW Pin Anti-Ringing Operation**



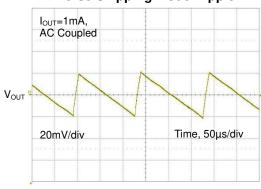
# **Line Transient Response**



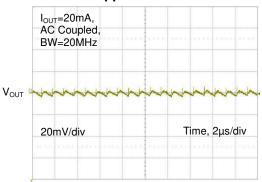
# **Load Transient Response**



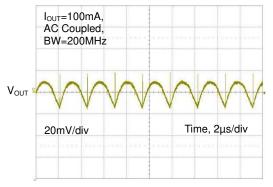
# **Pulse Skipping Mode Ripple**



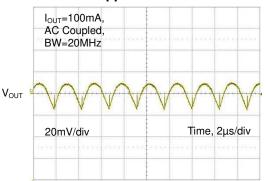
Ripple and Noise





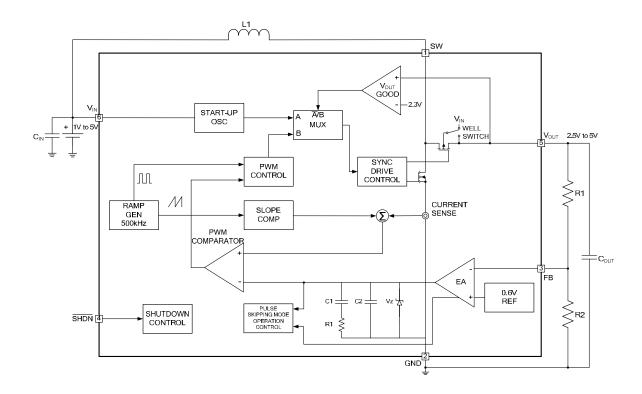


Ripple and Noise



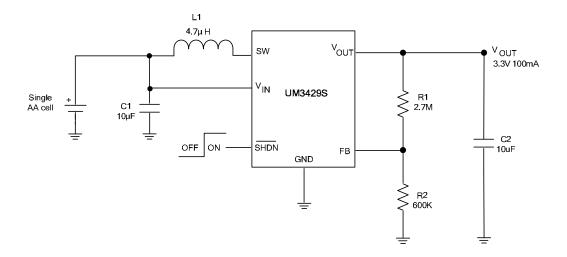


# **Block Diagram**



# **Typical Application**

Single AA cell to 3.3 V





# **Function Description**

The UM3429S is a synchronous rectified, 500KHz fixed frequency, step-up DC/DC converter in low profile SOT23-6 package. It features start-up voltage low to 0.85V, low R<sub>DS(ON)</sub> internal MOSFET switches, current mode PWM controller and 0.6V internal reference voltage. Refer to the Block Diagram for better understanding.

#### Low Voltage Start-up

The UM3429S has an independent start-up oscillator. When the input voltage rises to 0.85V, the oscillator starts up. The frequency and duty cycle of the oscillator will be set to a fixed one (Typically: the frequency is 500kHz and the duty is 60%). In this status, the chip is in the open loop operation.

The device gets its start-up bias from  $V_{IN}$ . Once  $V_{OUT}$  exceeds  $V_{IN}$ , bias comes from  $V_{OUT}$ . The chip is still in the open loop operation in this status.

When the output voltage rises to 2.3V, the chip will switch to closed loop. The chip enters normal operation then.

# **Anti-Ringing Control**

An internal  $150\Omega$  resistor will be connected from SW to  $V_{IN}$  to damp resonant circuit formed by L and  $C_{SW}$  when the inductor current is in the discontinuous mode. That eliminates switch ringing and reduces EMI interference.

# **Pulse Skipping Mode Operation**

At very light loads, the UM3429S automatically enters Pulse Skipping Mode. In the Pulse Skipping Mode, the inductor current may reach zero or reverse on each pulse. The PWM control loop will automatically skip pulses to maintain output regulation. That improves the efficiency of the converter and saves energy of the battery.

## **Output Disconnection**

The UM3429S is designed to allow true output disconnection by eliminating body diode conduction of the internal PMOS rectifier. This allows  $V_{\text{OUT}}$  to go to 0V during shutdown, drawing zero current form the input source. This function is realized by the well switch that connects the substrate to  $V_{\text{IN}}$ . Please refer to the Block Diagram for better understanding.

#### **Applications Information**

#### **Output Voltage Setting**

The external resistor divider sets the output voltage. Choose R2 around  $300k\Omega$  for optimal transient response and feedback leakage current.  $V_{OUT}$  is set by:

$$V_{OUT} = 0.6V \left(1 + \frac{R1}{R2}\right)$$

#### **Inductor Selection**

A 4.7µH inductor with DC current rating at least 1A is recommended for most applications. Larger values of inductance will allow greater output current capability by reducing the inductor ripple current. Increasing the inductance above 6.8µH will increase size while providing little



improvement in output current capability.

For best efficiency, the inductor DC resistance shall be as small as possible to reduce the I<sup>2</sup>R power losses. As the switching frequency is up to 500KHz, inductor losses are closely related to the magnetic core materials. High frequency ferrite core inductors are preferred to comparatively cheap powered iron core ones. To minimize radiated noise, use a toroid, pot core or shielded bobbin inductor. See Table 1 for some suggested inductors and suppliers.

**Table 1. Recommended Inductors** 

Part	L (µH)	Max DCR (mΩ)	Height (mm)	Supplier
74404024047	4.7	175	1.2	
74404024068	6.8	300	1.2	
74404032047	4.7	96	1.5	
74404032068	6.8	120	1.5	
CDRH3D16-4R7	4.7	105	1.8	Sumida
CR43-4R7	4.7	109	3.5	www.sumida.com
DS1608-472	4.7	60	2.9	Coilcraft
DO1608C-472	4.7	90	2.9	www.coilcraft.com
LQH32CN4R7M24	4.7	195	2.2	Murata
LQM21PN4R7MGHL	4.7	275	0.9	www.murata.com

# **Input and Output Capacitor Selection**

Low ESR capacitors should be used to minimize the output voltage ripple, input switching noise and the peak current drawn from the battery. Multilayer ceramic capacitors are an excellent choice as they have extremely low ESR and are available in small footprints. X5R and X7R dielectric materials are recommended.

A  $4.7\mu F$  to  $10\mu F$  input and output capacitor is sufficient for most applications. To minimize the output voltage ripple and improve the transient response, an output capacitor up to  $22\mu F$  or larger can be used. Table 2 below shows a list of several ceramic capacitor suppliers.

**Table 2. Recommended Capacitor Suppliers Information** 

Supplier	Website		
AVX	www.avxcorp.com		
Murata	www.murata.com		
Fenghua	www.china-fenghua.com		
Samsung Electro-Mechanics	www.samsungsem.com		

#### **Thermal Consideration**

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula:

 $\hat{P}_{D(MAX)} = (\hat{T}_{J(MAX)} - T_A) / \theta_{JA}$ 

where  $T_{J(MAX)}$  is the maximum junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction to ambient thermal resistance.

For recommended operating condition specifications of the UM3429, the maximum junction temperature is  $150^{\circ}$ C and  $T_A$  is the ambient temperature. The junction to ambient thermal resistance,  $\theta_{JA}$ , is layout dependent.

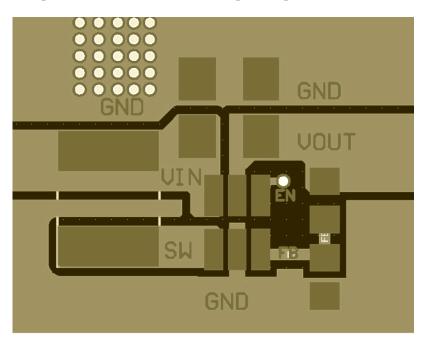
The maximum power dissipation depends on the operating ambient temperature for fixed  $T_{J(MAX)}$  and thermal resistance,  $\theta_{JA}$ .



# **Layout Guidance**

When laying out the PC board, the following suggestions should be taken to ensure proper operation of the UM3429.

- 1. Consideration should be taken first to place  $C_{OUT}$  as closely as possible to the  $V_{OUT}$  and GND pins.
- 2. The power traces, including the GND, SW,  $V_{\rm IN}$  and  $V_{\rm OUT}$  should be kept short, direct and wide to allow large current flow.
- 3. Connect the input capacitor  $C_{IN}$  to the GND pin as closely as possible to get good power filter effect and reduce ground bounce.
- 4. Keep the switching node away from the sensitive FB node.
- 5. Do not trace signal line under inductor.
- 6. Keep the GND plane under the converter as complete as possible in double-sided PCB board.

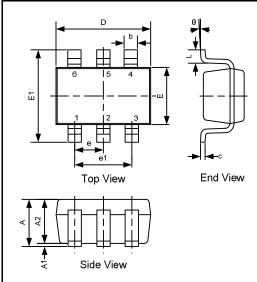




# **Package Information**

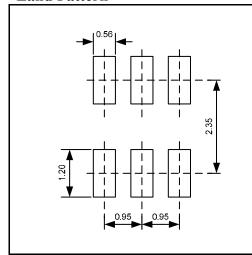
UM3429S: SOT23-6

**Outline Drawing** 



DIMENSIONS						
Cb al	MILLIMETERS			INCHES		
Symbol	Min	Тур	Max	Min	Тур	Max
A	1.013	1.15	1.40	0.040	0.045	0.055
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	1.00	1.10	1.30	0.039	0.043	0.051
b	0.30	-	0.50	0.012	-	0.020
С	0.10	0.15	0.20	0.004	0.006	0.008
D	2.82	-	3.10	0.111	-	0.122
Е	1.50	1.60	1.70	0.059	0.063	0.067
E1	2.60	2.80	3.00	0.102	0.110	0.118
e	0.95REF			0.037REF		
e1	1.90REF			0.075REF		
L	0.30	-	0.60	0.012	-	0.024
θ	0°	-	8°	0°	-	8°

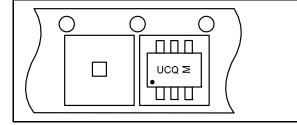
# **Land Pattern**



#### NOTES:

- 1. Compound dimension: 2.92×1.60;
- 2. Unit: mm;
- 3. General tolerance  $\pm 0.05$ mm unless otherwise specified;
- 4. The layout is just for reference.

**Tape and Reel Orientation** 





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